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<u>Diodes Incorporated</u> <u>ZXTN618MATA</u>

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Datasheet of ZXTN618MATA - TRANS NPN 20V 4.5A 3-DFN

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ZXTN618MA

#### 20V NPN LOW SATURATION TRANSISTOR

#### **Features and Benefits**

- BV<sub>CEO</sub> > 20V
- I<sub>C</sub> = 4.5A Continuous Collector Current
- Low Saturation Voltage (150mV max @ 1A)
- $R_{SAT} = 47 \text{ m}\Omega$  for a low equivalent On-Resistance
- h<sub>FE</sub> specified up to 6A for high current gain hold up
- Low profile 0.6mm high package for thin applications
- R<sub>θJA</sub> efficient, 60% lower than SOT23
- 4mm<sup>2</sup> footprint, 50% smaller than SOT23
- Lead-Free, RoHS Compliant (Note 1)
- Halogen and Antimony Free. "Green" Device (Note 2)
- Qualified to AEC-Q101 Standards for High Reliability

#### **Mechanical Data**

- Case: DFN2020B-3
- Case Material: Molded Plastic. "Green" Molding Compound.
- Terminals: Pre-Plated NiPdAu leadframe.
- Nominal Package Height: 0.6mm
- UL Flammability Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Weight: 0.01 grams (approximate)

#### **Applications**

- MOSFET Gate Driving
- DC-DC Converters
- Charging circuits
- Power switches
- Motor Control

#### DFN2020B-3



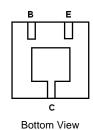




**Bottom View** 



Device Symbol



Pin-Out

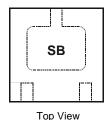
#### **Ordering Information**

I	Product	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
I	ZXTN618MATA	SB	7	8	3000

Notes:

- 1. No purposefully added lead.
- 2. Diodes Inc's "Green" policy can be found on our website at http://www.diodes.com

### **Marking Information**



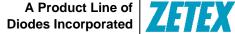
SB = Product Type Marking code



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### **Maximum Ratings** @ $T_A = 25$ °C unless otherwise specified

Parameter		Symbol	Limit	Unit	
Collector-Base Voltage		V <sub>CBO</sub>	40	V	
Collector-Emitter Voltage		V <sub>CEO</sub>	20		
Emitter-Base Voltage		V <sub>EBO</sub>	7		
Peak Pulse Current		I <sub>CM</sub>	12		
Continuous Collector Current	(Note 3)	1.	4.5	1 ,	
Continuous Collector Current	(Note 4)	- Ic	5	^	
Base Current		I <sub>B</sub>	1		

#### Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Unit		
Power Dissipation	(Note 3)	)	1.5 12	W	
Linear Derating Factor	(Note 4)	P <sub>D</sub>	2.45 19.6	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 3)	Б	83		
Thermal Resistance, Junction to Ambient	(Note 4)	$R_{\theta JA}$	51	°C/W	
Thermal Resistance, Junction to Lead (Note 5)		$R_{ heta JL}$	16.8		
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C	

Notes:

- 3. For a device surface mounted on 31mm x 31mm (10cm²) FR4 PCB with high coverage of single sided 1oz copper, in still air conditions; the device is measured when operating in a steady-state condition. The entire exposed collector pad is attached to the heatsink.
- 4. Same as note (3), except the device is measured at t ≤ 5 sec.
- 5. For a single device, thermal resistance from junction to solder-point (at the end of the drain lead).

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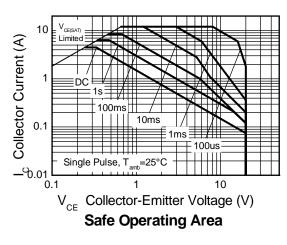
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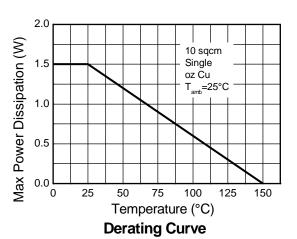


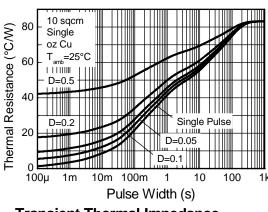


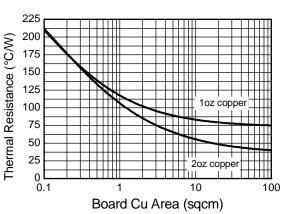
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#### **Thermal Characteristics**



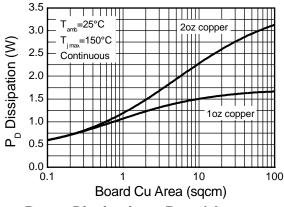






#### **Transient Thermal Impedance**

Thermal Resistance v Board Area



**Power Dissipation v Board Area** 



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### Electrical Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Base Breakdown Voltage	$BV_{CBO}$	40	100	-	V	I <sub>C</sub> = 100 μA
Collector-Emitter Breakdown Voltage (Note 6)	BV <sub>CEO</sub>	20	27	-	V	I <sub>C</sub> = 10 mA
Emitter-Base Breakdown Voltage	BV <sub>EBO</sub>	7	8.2	-	V	I <sub>E</sub> = 100 μA
Collector Cutoff Current	I <sub>CBO</sub>	-	-	100	nA	V <sub>CB</sub> = 30V
Emitter Cutoff Current	I <sub>EBO</sub>	-	-	100	. nA	$V_{EB} = 6V$
Collector Emitter Cutoff Current	I <sub>CES</sub>	-	-	100	nA	V <sub>CES</sub> = 16V
Static Forward Current Transfer Ratio (Note 6)	h <sub>FE</sub>	200 300 200 100	400 450 360 180	- - -	-	$\begin{split} &I_{C} = 10 \text{mA}, \ V_{CE} = 2 \text{V} \\ &I_{C} = 200 \text{mA}, \ V_{CE} = 2 \text{V} \\ &I_{C} = 2 \text{A}, \ V_{CE} = 2 \text{V} \\ &I_{C} = 6 \text{A}, \ V_{CE} = 2 \text{V} \end{split}$
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>	- - -	8 90 115 190 210	15 150 135 250 300	mV	$\begin{split} I_C = & 0.1A, \ I_B = 10 \text{mA} \\ I_C = & 1A, \ I_B = 10 \text{mA} \\ I_C = & 2A, \ I_B = 50 \text{mA} \\ I_C = & 3A, \ I_B = 100 \text{mA} \\ I_C = & 4.5A, \ I_B = 125 \text{mA} \end{split}$
Base-Emitter Turn-On Voltage (Note 6)	V <sub>BE(on)</sub>	-	0.88	0.97	V	I <sub>C</sub> = 4.5A, V <sub>CE</sub> = 2V
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>	-	0.98	1.07	V	I <sub>C</sub> = 4.5A, I <sub>B</sub> = 125mA
Output Capacitance	$C_{obo}$	-	23	30	pF	V <sub>CB</sub> = 10V. f = 1MHz
Transition Frequency	f <sub>T</sub>	100	140	-	MHz	V <sub>CE</sub> = 10V, I <sub>C</sub> = 50mA, f = 100MHz
Turn-On Time	t <sub>on</sub>	-	170	-	ns	$V_{CC} = 10V, I_C = 3A$
Turn-Off Time	t <sub>off</sub>	-	400	-	ns	$I_{B1} = I_{B2} = 10mA$

Notes: 6. Measured under pulsed conditions. Pulse width  $\leq$  300  $\mu$ s. Duty cycle  $\leq$  2%.

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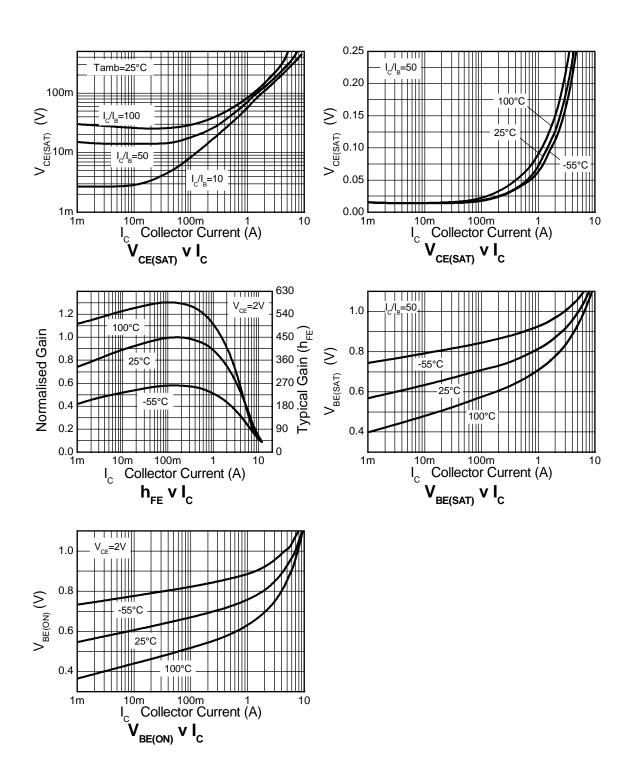
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### **Typical Electrical Characteristics**



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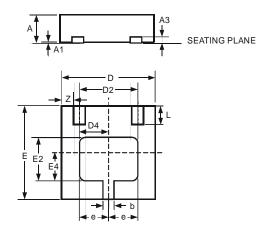
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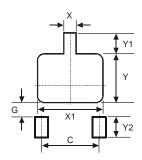
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## **Package Outline Dimensions**



DFN2020B-3						
Dim	Min	Max	Тур			
Α	0.57	0.63	0.60			
A1	0	0.05	0.02			
А3		_	0.152			
b	0.20	0.30	0.25			
D	1.95	2.075	2.00			
D2	1.22	1.42	1.32			
D4	0.56	0.76	0.66			
е		_	0.65			
Е	1.95	2.075	2.00			
E2	0.79	0.99	0.89			
E4	0.48	0.68	0.58			
L	0.25	0.35	0.30			
Z			0.225			
All Dimensions in mm						

#### **Suggested Pad Layout**



Dimensions	Value (in mm)		
С	1.30		
G	0.24		
Х	0.35		
X1	1.52		
Y	1.09		
Y1	0.47		
Y2	0.50		



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